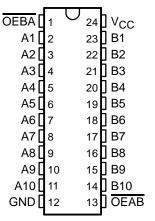
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- **EPIC™** (Enhanced-Performance Implanted **CMOS) Submicron Process**
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) > 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Power Off Disables Inputs/Outputs, Permitting Live Insertion
- **Supports Mixed-Mode Signal Operation on** All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) **Packages**

DB, DW, OR PW PACKAGE (TOP VIEW)



description

This 10-bit bus transceiver is designed for 2.7-V to 3.6-V V_{CC} operation.

The SN74LVC861A is designed for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing.

This device allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic levels at the output-enable (OEAB and OEBA) inputs.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74LVC861A is characterized for operation from -40°C to 85°C.

FUNCTION TABLE

INP	UTS	OPERATION						
OEAB	OEBA	OPERATION						
L	Н	A data to B bus						
Н	L	B data to A bus						
Н	Н	Isolation						
L	L	Latch A and B (A = B)						

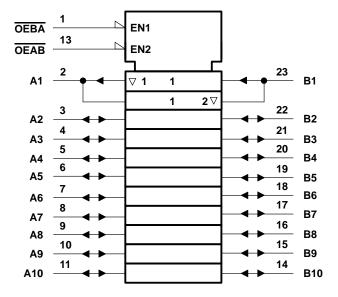


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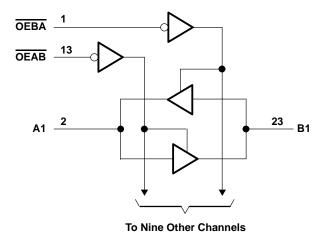


logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Input voltage range, V _I : Except I/O ports (see Note 1)	
I/O ports (see Notes 1 and 2)	
Voltage range applied to any output in the high-impedance or po	wer-off state, V _O
(see Note 1)	
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	-0.5 V to $V_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$ (see Note 2)	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3): DB package	104°C/W
DW package	81°C/W
PW package	120°C/W
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 2. The value of V_{CC} is provided in the recommended operating conditions table.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
V-00	Supply voltage	Operating	2	3.6	V	
VCC	Supply voltage	Data retention only	1.5		V	
VIH	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		V	
V _{IL}	Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	V	
٧ _I	Input voltage		0	5.5	V	
V _O O	Output voltage	High or low state	0	VCC	-	
		3 state	0	5.5		
ЮН	High-level output current	V _{CC} = 2.7 V		-12	mA	
		V _{CC} = 3 V		-24	IIIA	
loL	Low-level output current	V _{CC} = 2.7 V		12	mA	
	Low-level output current	V _{CC} = 3 V		24	.] '''A	
Δt/Δν	Input transition rise or fall rate			10	ns/V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 4: Unused inputs must be held high or low to prevent them from floating.



SN74LVC861A 10-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAI	RAMETER	TEST CONDITIONS		VCC	MIN	TYP [†]	MAX	UNIT	
		I _{OH} = -100 μA		2.7 V to 3.6 V	V _{CC} -0.2				
\ \ _{\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\}		I _{OH} = -12 mA		2.7 V	2.2			٧	
VOH				3 V	2.4				
		I _{OH} = -24 mA		3 V	2.2				
	I _{OL} = 100 μA		2.7 V to 3.6 V			0.2			
V_{OL}		I _{OL} = 12 mA		2.7 V			0.4	V	
		I _{OL} = 24 mA		3 V			0.55		
II		V _I = 0 to 5.5 V		3.6 V			±5	μΑ	
l _{off}		V _I or V _O = 5.5 V		0			±10	μΑ	
loz‡		V _O = 0 to 5.5 V		3.6 V			±10	μΑ	
		$V_I = V_{CC}$ or GND	IO = 0	3.6 V			10		
lcc	$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}$					10	μΑ		
Δlcc		One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND	2.7 V to 3.6 V			500	μΑ	
Ci	Control inputs	$V_I = V_{CC}$ or GND		3.3 V		5		pF	
C _{io}	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		7		pF	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		UNIT
	(INFO1)	(001-01)	MIN	MAX	MIN	MAX	
^t pd	A or B	B or A	1.3	6.4		6.8	ns
^t en	OEAB or OEBA	A or B	1	7		8.2	ns
^t dis	OEAB or OEBA	A or B	1.7	5.9		6.6	ns
$t_{sk(o)}^{\P}$				1			ns

[¶] Skew between any two outputs of the same package switching in the same direction. This parameter is warranted but not production tested.

operating characteristics, $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$

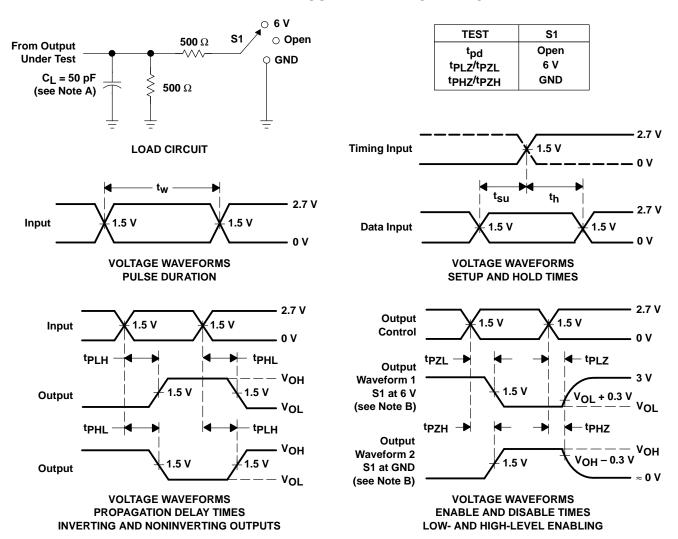
PARAMETER			TEST C	ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per transceiver	Outputs enabled	$C_L = 0,$ $f = 10$	f = 10 MHz	29	pF
		Outputs disabled		1 = 10 WITZ	5	



[‡] For I/O ports, the parameter IOZ includes the input leakage current.

[§] This applies in the disabled state only.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 2.5 \ ns$, $t_f \leq 2.5 \ ns$.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpzL and tpzH are the same as ten.
- F. tpLZ and tpHZ are the same as t_{dis}.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

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